

Symbol	Parameter		FQD17P06 / FQU17P06	Units
V _{DSS}	Drain-Source Voltage		-60	V
ID	Drain Current - Continuous ($T_C = 25^{\circ}C$) - Continuous ($T_C = 100^{\circ}C$)		-12	А
			-7.6	A
I _{DM}	Drain Current - Pulsed	(Note 1)	-48	А
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	300	mJ
I _{AR}	Avalanche Current	(Note 1)	-12	А
E _{AR}	Repetitive Avalanche Energy	(Note 1)	4.4	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-7.0	V/ns
PD	Power Dissipation ($T_A = 25^{\circ}C$) *		2.5	W
	Power Dissipation (T _C = 25°C)		44	W
	- Derate above 25°C		0.35	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

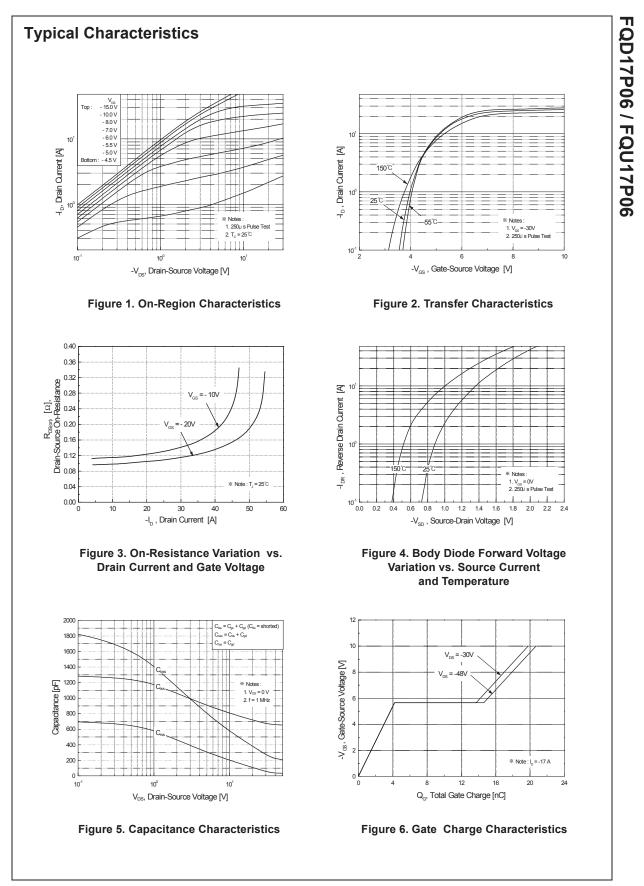
Thermal Characteristics

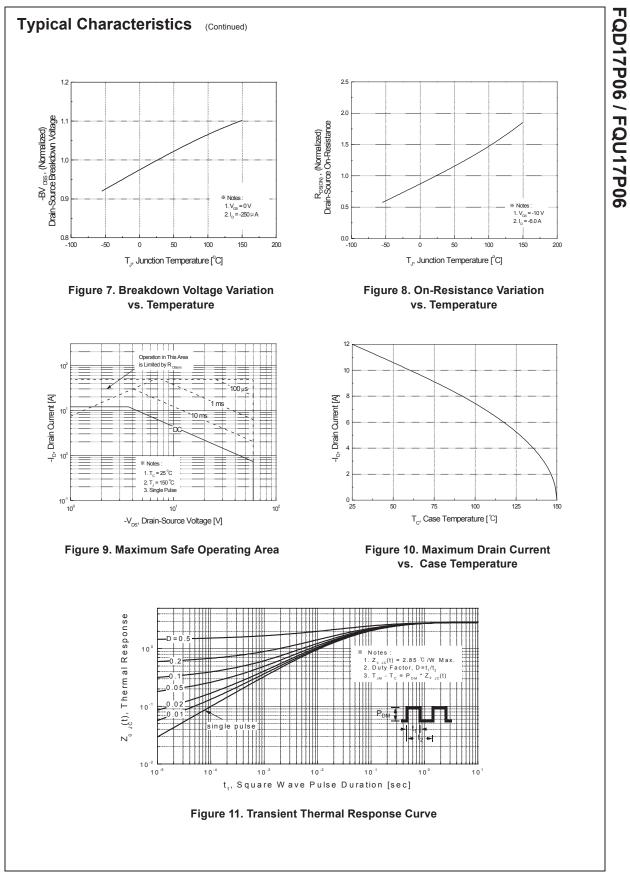
Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		2.85	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient *		50	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		110	°C/W

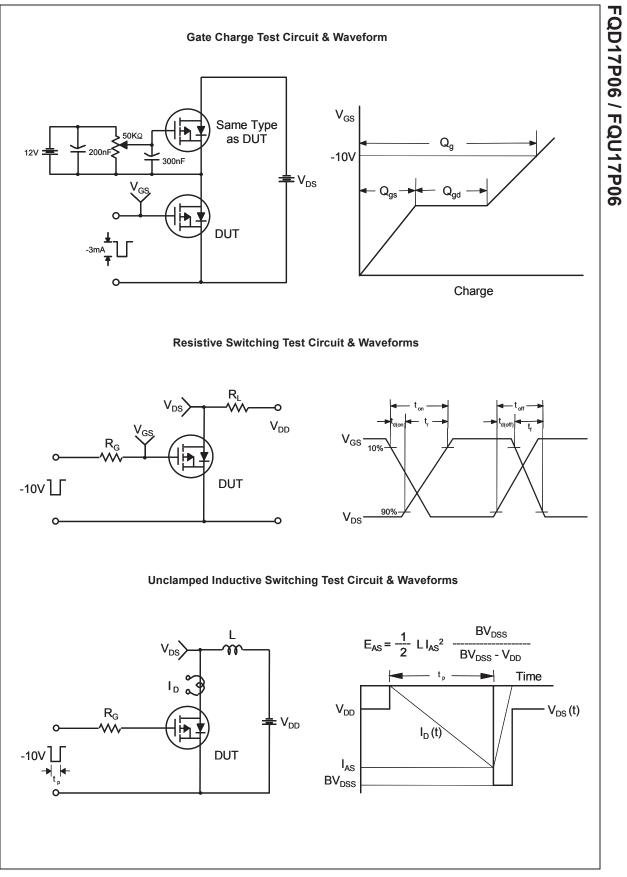
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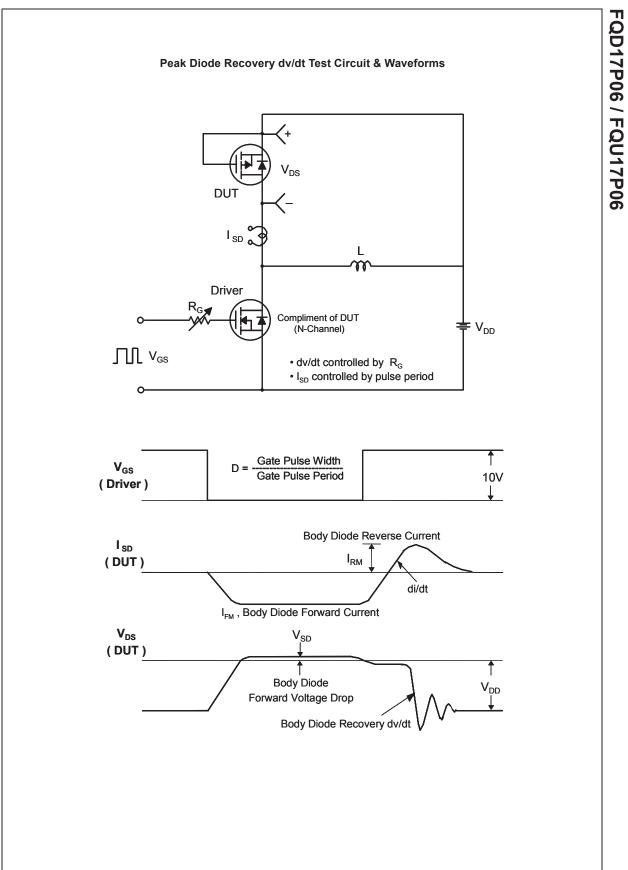
Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA	-60			V
ΔBV _{DSS}	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		-0.06		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -60 V, V _{GS} = 0 V			-1	μA
		$V_{DS} = -48 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$			-10	μΑ
GSSF	Gate-Body Leakage Current, Forward	V _{GS} = -25 V, V _{DS} = 0 V			-100	nA
GSSR	Gate-Body Leakage Current, Reverse	V_{GS} = 25 V, V_{DS} = 0 V			100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} , I_D = -250 μ A	-2.0		-4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = -10 V, I _D = -6.0 A		0.11	0.135	Ω
JFS	Forward Transconductance	$V_{DS} = -30 \text{ V}, I_D = -6.0 \text{ A}$ (Note 4)		8.7		S
Dynami C _{iss}	ic Characteristics Input Capacitance			690	900	pF
		$V_{DS} = -25 V, V_{GS} = 0 V,$				•
C _{oss} C _{rss}	Output Capacitance Reverse Transfer Capacitance	f = 1.0 MHz		325 80	420 105	pF pF
d(on)	ng Characteristics Turn-On Delay Time	V _{DD} = -30 V, I _D = -8.5 A,		13	35	ns
d(on)	Turn-On Delay Time	$V_{DD} = -30 V I_D = -8.5 A$		13	35	ns
r	Turn-On Rise Time	$R_G = 25 \Omega$		100	210	ns
d(off)	Turn-Off Delay Time	-		22	55	ns
f	Turn-Off Fall Time	(Note 4, 5)		60	130	ns
ל ^g	Total Gate Charge	V _{DS} = -48 V, I _D = -17 A,		21	27	nC
ସୁ _{gs}	Gate-Source Charge	V _{GS} = -10 V		4.2		nC
ე _{gd}	Gate-Drain Charge	(Note 4, 5)		10		nC
Drain-S	ource Diode Characteristics an	nd Maximum Ratings				
S	Maximum Continuous Drain-Source Dic	ode Forward Current			-12	Α
SM	Maximum Pulsed Drain-Source Diode F				-48	Α
/ _{SD}	Drain-Source Diode Forward Voltage	V_{GS} = 0 V, I _S = -12 A			-4.0	V
rr	Reverse Recovery Time	V _{GS} = 0 V, I _S = -17 A,		92		ns
ე _ო	Reverse Recovery Charge	$dI_{F} / dt = 100 A/\mu s$ (Note 4)		0.32		μC
L = 2.4mH, I I _{SD} ≤ -17A,	ating : Pulse width limited by maximum junction temper $A_S = -12A$, $V_{DD} = -25V$, $R_G = 25 \Omega$, Starting $T_J = 25^{\circ}C$ di/dt $\leq 300A/\mu_S$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^{\circ}C$ Pulse width $\leq 300\mu_S$, Duty cycle $\leq 2\%$ dependent of operating temperature					

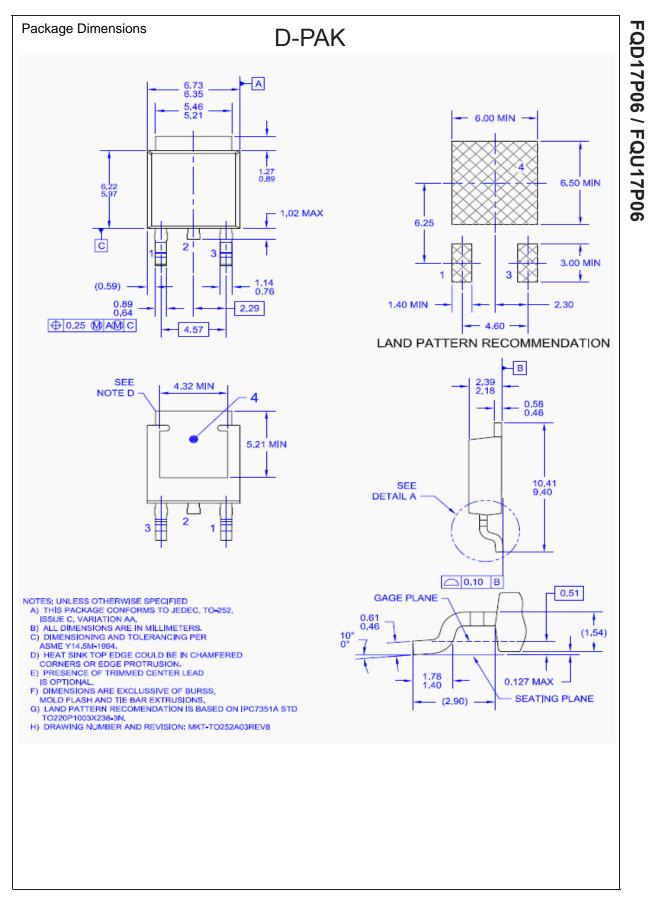
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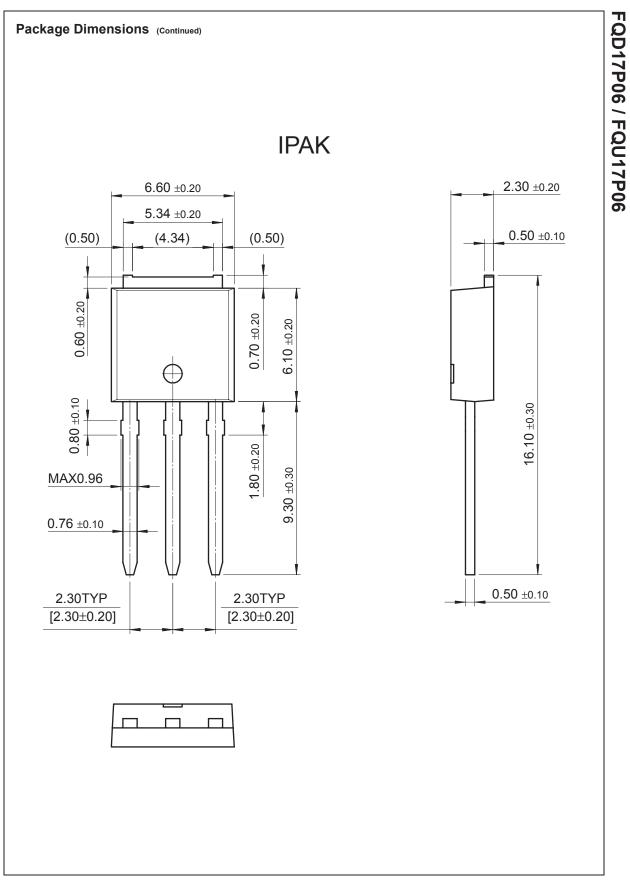












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